



#### 25V NPN HIGH PERFORMANCE TRANSISTOR IN PowerDI3333-8

#### **Features**

- BV<sub>CEO</sub> > 25V
- Small Form Factor Thermally Efficient Package.
   Enables Higher Density End Products
- I<sub>C</sub> = 3A High Continuous Current
- I<sub>CM</sub> = 8A Peak Pulse Current
- Low Saturation Voltage V<sub>CE(SAT)</sub> < 200mV @ 1A</li>
- Complementary PNP Type: DXTP07025BFG
- Rated to +175°C Ideal For High Temperature Environment
- Wettable Flank For Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

#### **Mechanical Data**

- Case: PowerDI<sup>®</sup>3333-8
- Case Material: Molded Plastic. "Green" Molding Compound.
   UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Solderable per MIL-STD-202, Method 208 <a>@3</a>
- Weight: 0.03 grams (Approximate)

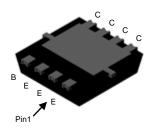
### **Applications**

- Load Switch
- Linear Regulator

PowerDI3333-8 (SWP) (Type UX)

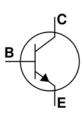






Bottom View

**Equivalent Circuit** 



Device Symbol

### **Ordering Information** (Note 4)

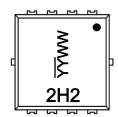
Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DXTN07025DBFG-7	2H2	7	12	2,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Hallogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**

PowerDI3333-8 (SWP) (Type UX)



2H2= Product Type Marking Code

YYWW = Date Code Marking

YY = Last Two Digits of Year (ex: 18 = 2018)

WW = Week Code (01 to 53)



# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	35	V
Collector-Emitter Voltage	V <sub>CEO</sub>	25	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ic	3	Α
Peak Pulse Current	I <sub>CM</sub>	8	Α

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
	(Note 5)		0.9	W
Power Dissipation	(Note 6)	P <sub>D</sub>	2.1	W
	(Note 7)		3.1	W
	(Note 5)	R <sub>0JA</sub>	140	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)		65	°C/W
	(Note 7)		44	°C/W
Thermal Resistance, Junction to Leads (Note 8	R <sub>0JL</sub>	8.5	°C/W	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +175	°C	

# ESD Ratings (Note 9)

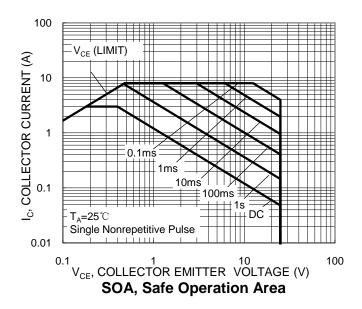
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

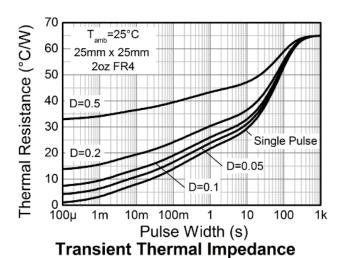
Notes: For a device mounted with the collector tab on MRP FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.

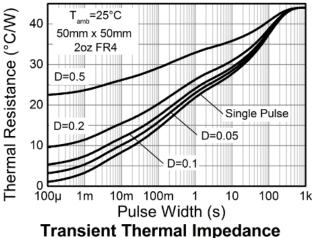
- Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
- Same as Note 5, except the device is mounted on 50mm x 50mm 2oz copper.
- Thermal resistance from junction to solder-point (at the collector tab). Refer to JEDEC specification JESD22-A114 and JESD22-A115.

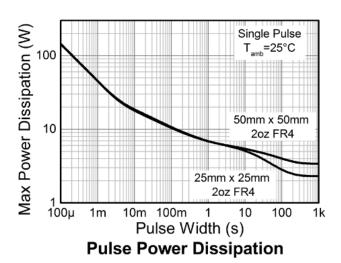


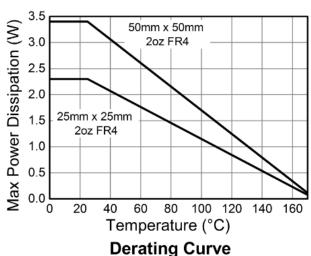
## **Thermal Characteristics and Derating Information**













# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	35	136	_	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage (Note 10)	BV <sub>CEO</sub>	25	47	_	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8.4	_	V	I <sub>E</sub> = 100μA
Collector Cut-Off Current	Ісво	_	_	20	nA	V <sub>CB</sub> = 30V
Collector Cut-Off Current		_	_	10	μA	$V_{CB} = 30V, T_A = +125^{\circ}C$
Emitter Cut-Off Current	I <sub>EBO</sub>	_	_	20	nA	V <sub>EB</sub> = 6V
Collector-Emitter Saturation Voltage (Note 10)	.,	_	69	200	mV	$I_C = 1A$ , $I_B = 100mA$
Collector-Efflitter Saturation Voltage (Note 10)	V <sub>CE</sub> (SAT)	_	180	400	mV	$I_C = 3A$ , $I_B = 300mA$
Base-Emitter Saturation Voltage (Note 10)	V <sub>BE(SAT)</sub>	_	0.86	1.1	V	$I_C = 1A$ , $I_B = 100mA$
Base-Emitter Turn-On Voltage (Note 10)	V <sub>BE(ON)</sub>	_	0.78	1	V	I <sub>C</sub> = 1A, V <sub>CE</sub> = 2V
	h <sub>FE</sub>	70	198	_	_	I <sub>C</sub> = 50mA, V <sub>CE</sub> = 2V
DC Current Coin (Note 10)		100	191	300	_	$I_C = 1A$ , $V_{CE} = 2V$
DC Current Gain (Note 10)		75	180	_	_	$I_C = 2A$ , $V_{CE} = 2V$
		15	98	_	_	$I_C = 6A$ , $V_{CE} = 2V$
Current Gain-Bandwidth Product	f <sub>T</sub>	150	240	_	MHz	V <sub>CE</sub> = 5V, I <sub>C</sub> = 100mA, f = 100MHz
Switching Times	t <sub>ON</sub>	_	55	_	ns	I <sub>C</sub> = 500mA, V <sub>CC</sub> = 10V,
vicining rimes	t <sub>OFF</sub>	_	300	_	ns	$I_{B1} = -I_{B2} = 50 \text{mA}$
Output Capacitance	Сово	_	25	50	pF	V <sub>CB</sub> = 10V, f = 1MHz

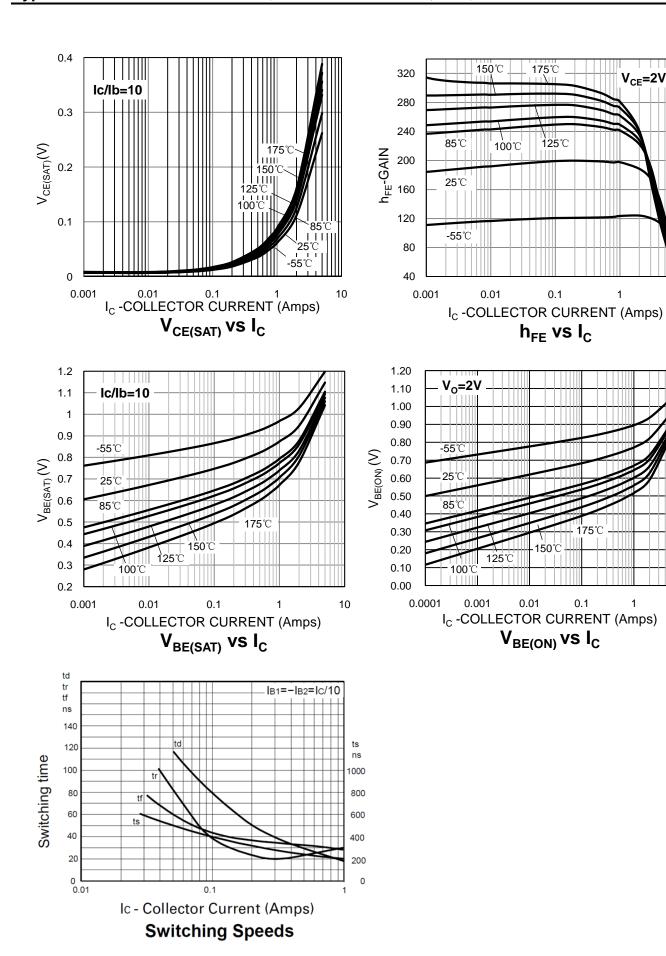
Note: 10. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

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### Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

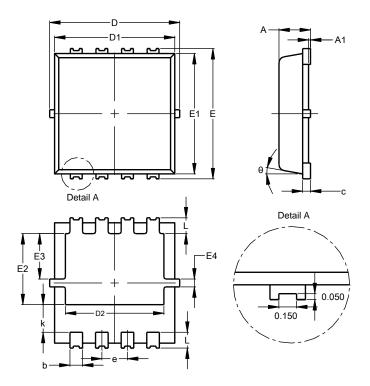




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### PowerDI3333-8 (SWP) (Type UX)

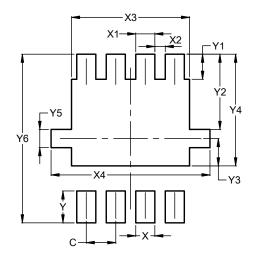


PowerDI3333-8 (SWP)					
(Type UX) ´					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
<b>A</b> 1	0.00	0.05	-		
b	0.25	0.40	0.32		
C	0.10	0.25	0.15		
D	3.20	3.40	3.30		
D1	2.95	3.15	3.05		
D2	2.30	2.70	2.50		
Е	3.20	3.40	3.30		
E1	2.95	3.15	3.05		
E2	1.60	2.00	1.80		
E3	0.95	1.35	1.15		
E4	0.10	0.30	0.20		
е		_	0.65		
k	0.50	0.90	0.70		
L	0.30	0.50	0.40		
θ	0°	12°	10°		
All Dimensions in mm					

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)				
С	0.650				
Х	0.420				
X1	0.420				
X2	0.230				
Х3	2.600				
X4	3.500				
Y	0.700				
Y1	0.550				
Y2	1.650				
Y3	0.600				
Y4	2.450				
Y5	0.400				
Y6	3.700				

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.



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